

Description

UMW UCC27324DR is power switch driver. It has a matching rise and fall time when charging and discharging the gate of the power switch.

UMW UCC27324DR has high latch resistance under all conditions in its rated power and voltage range. When noise spikes of up to 5V (either polarity) occur on the ground pin, the UMW UCC27324DR is not damaged. UMW UCC27324DR can accept reverse currents up to 500 mA to force back its output without damage or logic confusion. All ports are fully protected by up to 2.0 kV electrostatic discharge (ESD).

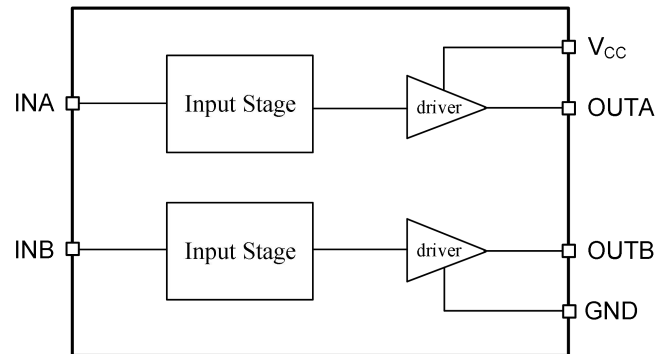
Applications

- Switch-Mode Power Supplies
- line drivers
- Pulse transformer driver
- Driving MOSFETs and IGBTs
- Motor drives
- pulse generator
- Switch-Mode Power Supplies
- DC-to-DC Converters
- class D switching amplifier

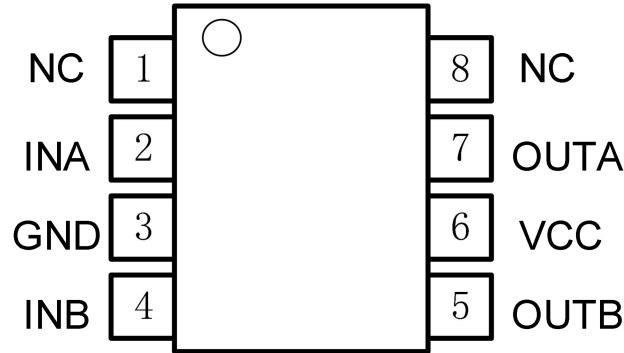
Features

- Latch Protection: withstand 0.5 A reverse current
- Ability to Handle Negative Voltages (-10 V) at Inputs
- Low Output Impedance
- Two Independent Gate-Drive Channel
- 4-A Peak Output Current
- 4.5 to 25-V Single-Supply Range
- High Ability of driving capacitive load
- Rise/Fall time matching
- Operating Temperature Range of -40 to 125° C
- Turn on/Turn off Delays:
 - Ton/Toff =25ns/25ns

Pin Configuration



Pin Configuration and Functions



8-Pin SOIC8 Package Top View

Pin Functions

PIN	NAME	DESCRIPTION
1	NC	--
2	INA	Input to Channel A
3	GND	Ground: All signals are referenced to this pin.
4	INB	Input to Channel B
5	$\overline{\text{OUTB}}$	Output of Channel B
6	VCC	Bias supply input
7	$\overline{\text{OUTA}}$	Output of Channel A
8	NC	--

Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. All voltages are with respect to GND unless otherwise noted, Currents are positive into, negative out of the specified terminal, environment temperature is 25 °C.

Symbol	Definition	MIN	MAX	UNIT
V _{CC}	Supply voltage range	—	25	V
V _{IN}	INA, INB voltage	GND-10	V _{CC} +0.3	
ESD	Human body model (HBM)	—	2000	V
	Charged device model (CDM)	—	500	V
PD	SOIC package power (TA ≤70°C)	—	470	mW
T _J	Operating junction temperature	—	+150	°C
T _S	Storage temperature	-45	+150	
V _{CC}	Supply voltage range	4.5	20	V
T _C	ambient temperature	-40	125	°C

Electrical Characteristics

TA= 25°C, VCC=15V(unless otherwise noted)

Symbol	Definition	MIN	TYP	MAX	UNIT
V _{IH}	Input signal high threshold	2.4	—	—	V
V _{IL}	Input signal low threshold	—	—	0.8	V
I _{IN+}	Input current(V _{IN} =5V)	—	50	—	μA
I _{IN-}	Input current(V _{IN} =0V)	—	—	1	μA
V _{OH}	High output voltage	VCC-0.025	—	—	V
V _{OL}	Low output voltage	—	—	0.025	V
R _{OH}	Output pullup resistance(I _O =100mA)	—	0.7	—	Ω
R _{OL}	Output pulldown resistance(I _O =100mA)	—	0.4	—	Ω
I _{PK}	Peak output source current	—	4	—	A
I _{REV}	Reverse current that latch protection can withstand(Working cycle≤2%,t≤300us)	—	>0.5	—	A
t _R	Rise time(C _{LOAD} =1800pF)	—	—	10	ns
t _F	Fall time(C _{LOAD} =1800pF)	—	—	10	ns
t _{ON}	Turn-on propagation delay(C _{LOAD} =1800pF)	—	25	35	ns
t _{OFF}	Turn-off propagation delay(C _{LOAD} =1800pF)	—	25	35	ns
I _{Q1}	VCC quiescent supply current(V _{INA} =V _{INB} =HIGH)	—	—	1	mA
I _{Q0}	VCC quiescent supply current(V _{INA} =V _{INB} =LOW)	—	—	1	mA

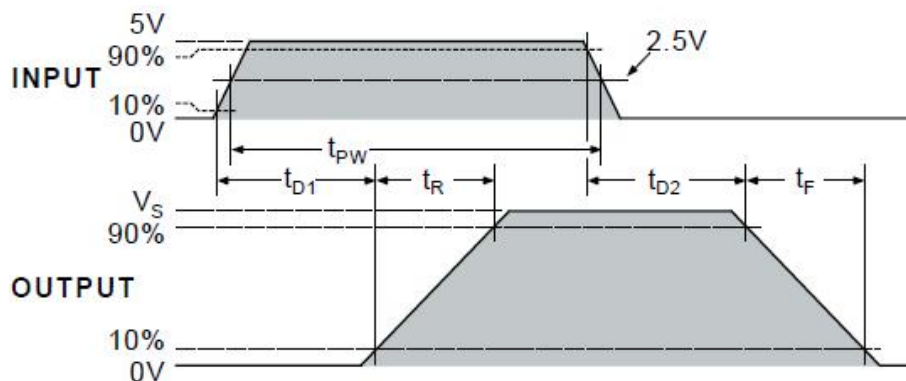
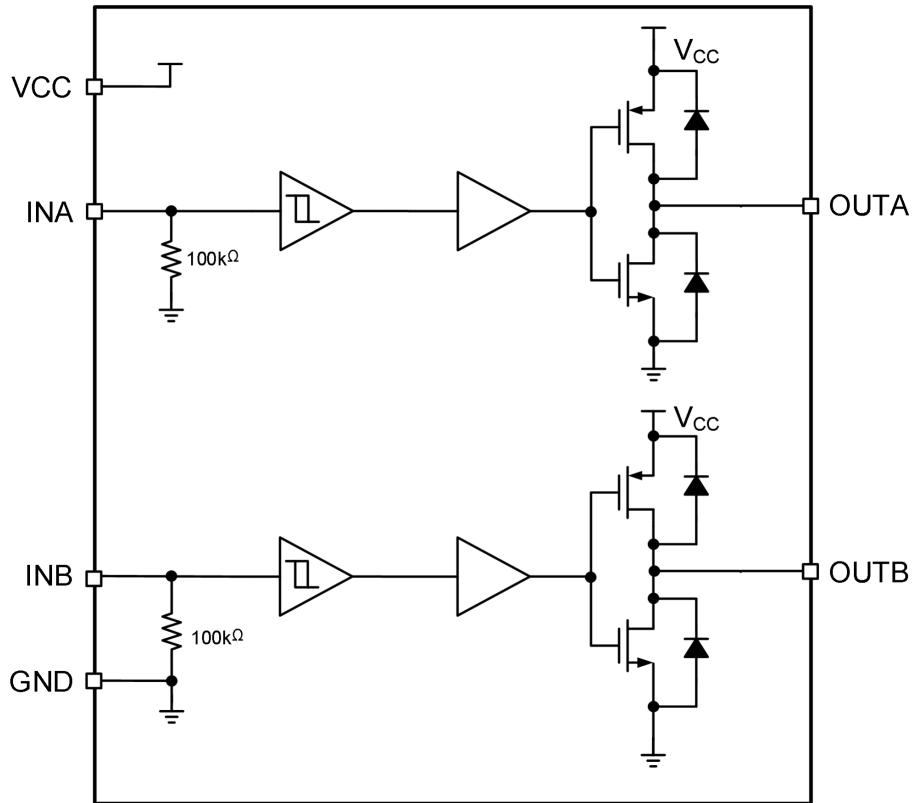


Figure 1 Input-Output waveform(non-inverting)

Functional Block Diagram



Typical Application

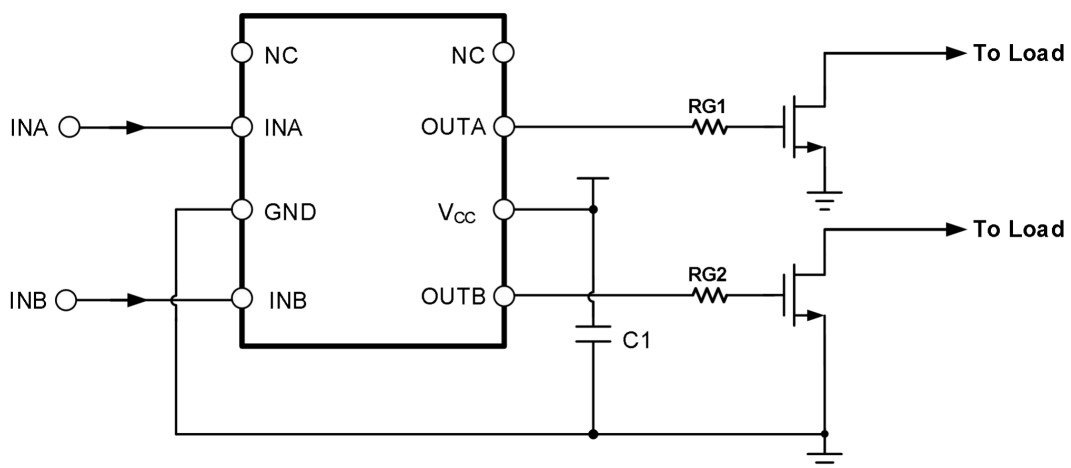
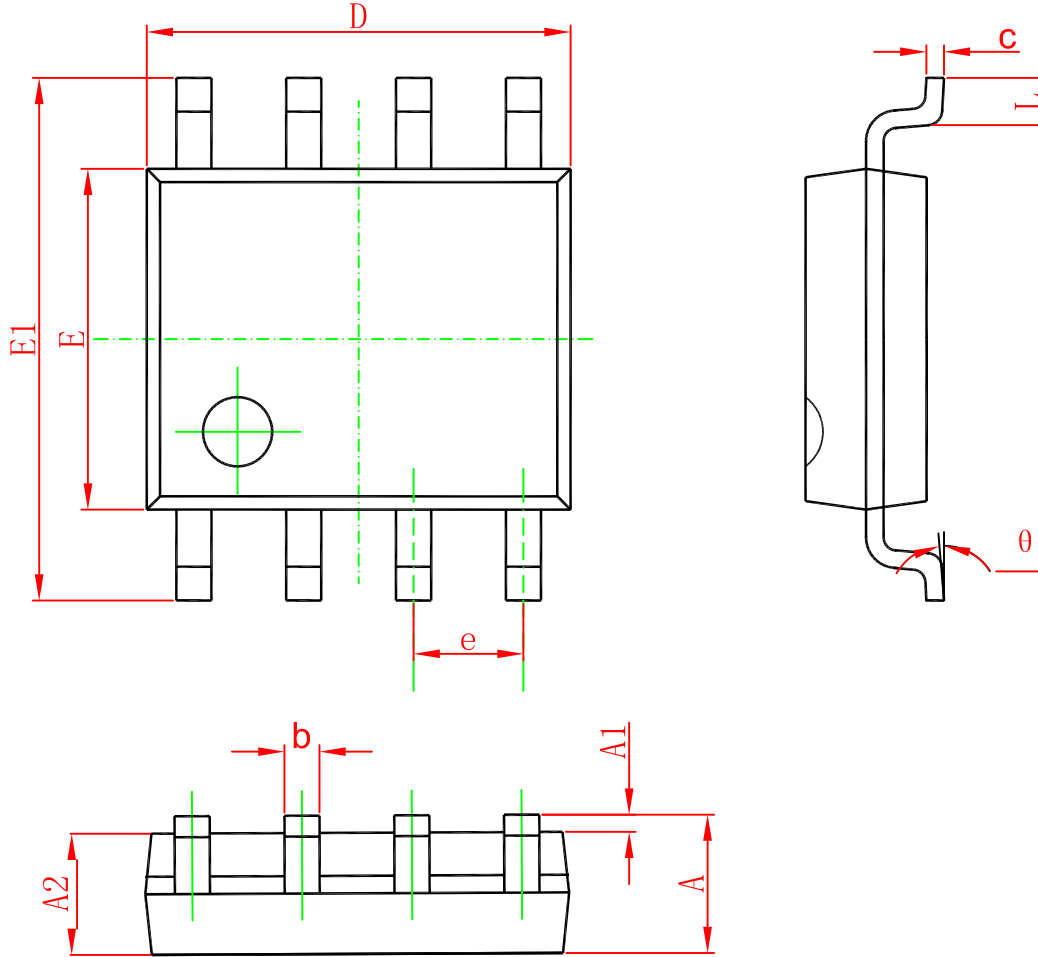


Figure 2 Typical Application Diagram of UCC27324DR

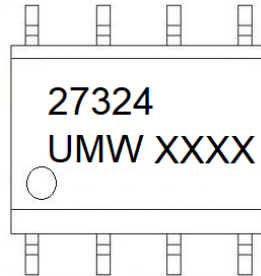
PACKAGING INFORMATION

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Marking



Ordering information

Order code	Package	Baseqty	Deliverymode
UMW UCC27324DR	SOP-8	2500	Tape and reel